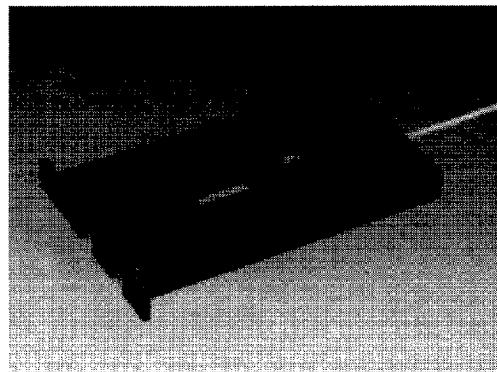


**Description**

The TRM5732AN is a lightwave transmitter for OC-12.

**Features**

- Complied with SONET/SDH standard
- DFB laser diode
- Operation from 1Mb/s to 622.08Mb/s at 1.3  $\mu$ m wavelength
- 50 $\Omega$ , AC-coupled interface
- Low-power-alarm and performance monitors

**Absolute Maximum Ratings ( $T_C = 25^\circ\text{C}$ )**

Item	Symbol	Rated Value	Units
Operating case temperature	$T_{opr}$	-40 to 75	°C
Storage case temperature	$T_{stg}$	-40 to 85	°C
Humidity (long-term)	—	55	%
Lead soldering temperature	$T_s$	250	°C
Lead soldering time	—	10	sec

**Optical Characteristics** (Unless otherwise indicated, measurement conditions are  $T_C = 25^\circ\text{C}$ , 50% duty-cycle data signal)

Item	Symbol	Min	Typ	Max	Units	Test Conditions
Average power output	$\overline{P_O}$	-1.75	0	1.75	dBm	622Mb/s, $T_C = 0$ to $65^\circ\text{C}$
		-2.0	0	2.0		156Mb/s, $T_C = -40$ to $75^\circ\text{C}$
Center wavelength	$\lambda_c$	1280	1310	1335	nm	622Mb/s, $T_C = 0$ to $65^\circ\text{C}$
						156Mb/s, $T_C = -40$ to $75^\circ\text{C}$
Spectral width	$\Delta\lambda$ (-20dB)	—	—	1	nm	20 dB down
Side mode suppression ratio	$S_r$	30	—	—	dB	
Extinction ratio	—	10	—	—	dB	$P_{OH} / P_{OL}$
Optical rise and fall times	$t_r, t_f$	—	—	0.5	ns	10 to 90% (50% duty cycle)
Optical path penalty	—	—	—	1	dB	max. 110 ps/nm (1.3 $\mu$ m) at 4% optical reflection

■ 4496205 0014483 519 ■

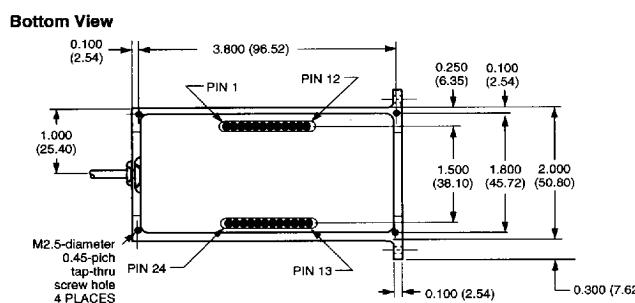
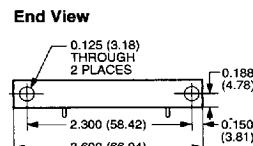
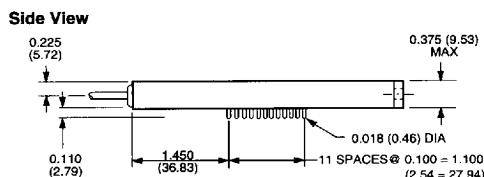
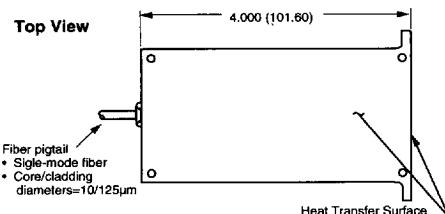
Part  
358 2 Hitachi America, Ltd. • 2000 Sierra Point Pkwy. • Brisbane, CA 94005-1835 • (415) 589-8300

**HITACHI®**

**Electrical Characteristics** (Unless otherwise indicated, measurement conditions are  
 $T_C = 25^\circ\text{C}$ , 50% duty-cycle data signal)

Item	Symbol	Min	Typ	Max	Units	Test Conditions
DC power supply voltage	V <sub>CC</sub>	4.75	5.0	5.25	V	
	V <sub>EE1</sub>	-4.95	-5.2	-5.45		
	V <sub>EE2</sub>	-2.1	-2.2	-2.3		
DC power supply current	I <sub>CC</sub>	—	—	800	mA	V <sub>CC</sub> = 5.0 V $\pm 5\%$
	I <sub>EE1</sub>	—	—	200		V <sub>EE1</sub> = -5.2 V $\pm 5\%$
	I <sub>EE2</sub>	—	—	1000		V <sub>EE2</sub> = -2.2 V $\pm 5\%$
Input data voltage	V <sub>IN</sub>	0.6	0.8	1.0	V <sub>pp</sub>	
Input transition time	T <sub>IN</sub>	—	—	T/4	ns	10 to 90% (50% duty cycle)
						T: bit-period

## Outline Drawings and Pin Descriptions



Pin	Description
1:	Case Ground (RF ground)
2:	Case Ground (RF ground)
3:	V <sub>EE1</sub>
4:	V <sub>EE2</sub>
5:	V <sub>CC</sub>
6:	Case Ground (RF ground)
7:	DATA (50 $\Omega$ , AC-coupled)
8:	Case Ground (RF ground)
9:	Case Ground (RF ground)
10:	Case Ground (RF ground)
11:	Case Ground (RF ground)
12:	No User Connection
13:	No User Connection
14:	Laser Bias Monitor (+)
15:	Laser Bias Monitor (-)
16:	Laser Backface Monitor (+)
17:	Laser Backface Monitor (-)
18:	Disable
19:	Case Ground (RF ground)
20:	Alarm Output
21:	Temperature Monitor (+)
22:	Temperature Monitor (-)
23:	Case Ground (RF ground)
24:	Case Ground (RF ground)

Tolerance:  $\pm 0.005$  in. ( $\pm 0.127$  mm)  
Dimension: inch (mm)

2

■ 4496205 0014484 455 ■

HITACHI®

Hitachi America, Ltd. • 2000 Sierra Point Pkwy. • Brisbane, CA 94005-1835 • (415) 589-8300

Part

2 359